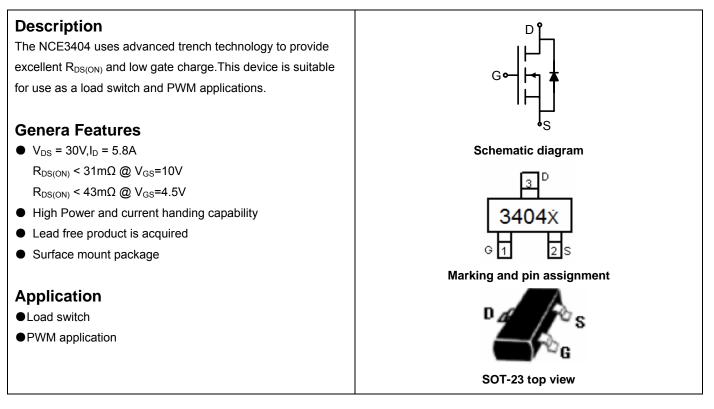


## NCE N-Channel Enhancement Mode Power MOSFET



### Package Marking and Ordering Information

U	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3404 X	NCE3404	SOT-23	Ø180mm	8 mm	3000 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	30	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I <sub>D</sub>	5.8	A	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	20	A	
Maximum Power Dissipation	PD	1.4	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	89	°C/W

## Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V Ι <sub>D</sub> =250μΑ	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1	μA



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Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.6	2.4	V
Drain Course On State Desistance	_	$V_{GS}$ =10V, I <sub>D</sub> =5A	-	25.5	31	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	36	43	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	-	15	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>Iss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V, F=1.0MHz	-	485.8	-	PF
Output Capacitance	C <sub>oss</sub>		-	65.2	-	PF
Reverse Transfer Capacitance	Crss		-	54	-	PF
Switching Characteristics (Note 4)	· · ·					
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =15V, R <sub>L</sub> =3Ω V <sub>GS</sub> =10V,R <sub>GEN</sub> =3Ω	-	5	-	nS
Turn-on Rise Time	tr		-	3	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	15	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.5	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =15V,I <sub>D</sub> =5.8A, V <sub>GS</sub> =10V	-	12.6	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.9	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	2.6	_	nC
Drain-Source Diode Characteristics						•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =5.8A	-	-	1.2	V
Diode Forward Current (Note 2)	ا <sub>S</sub>		-	-	5.8	Α

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production



on

10%

50%

90%

t<sub>d(off)</sub>

**INVERTED** 

**PULSE WIDTH** 

Figure 2:Switching Waveforms

90%

10%

90%

50%

t<sub>d(on)</sub>

Vout

VIN

10%

## **Typical Electrical and Thermal Characteristics**

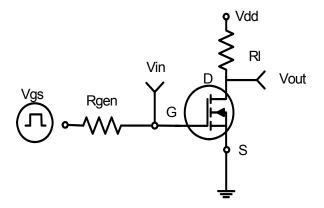
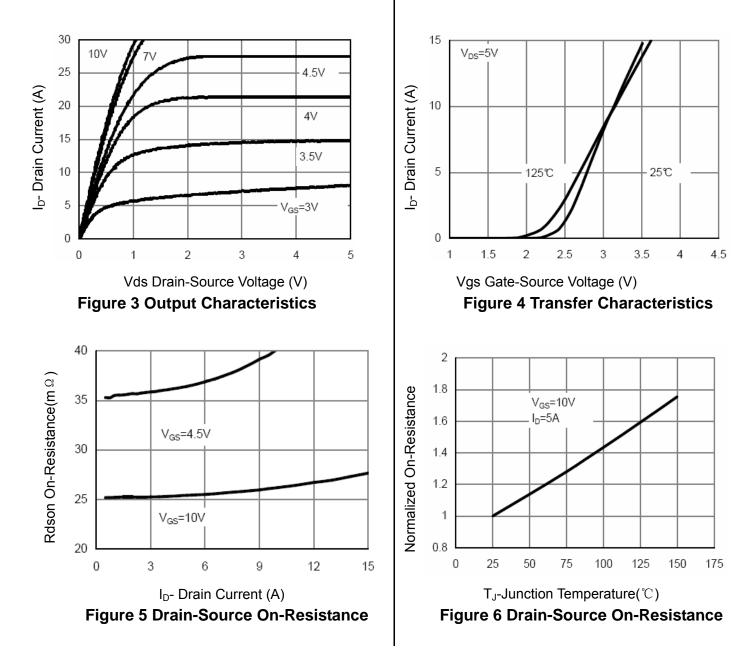


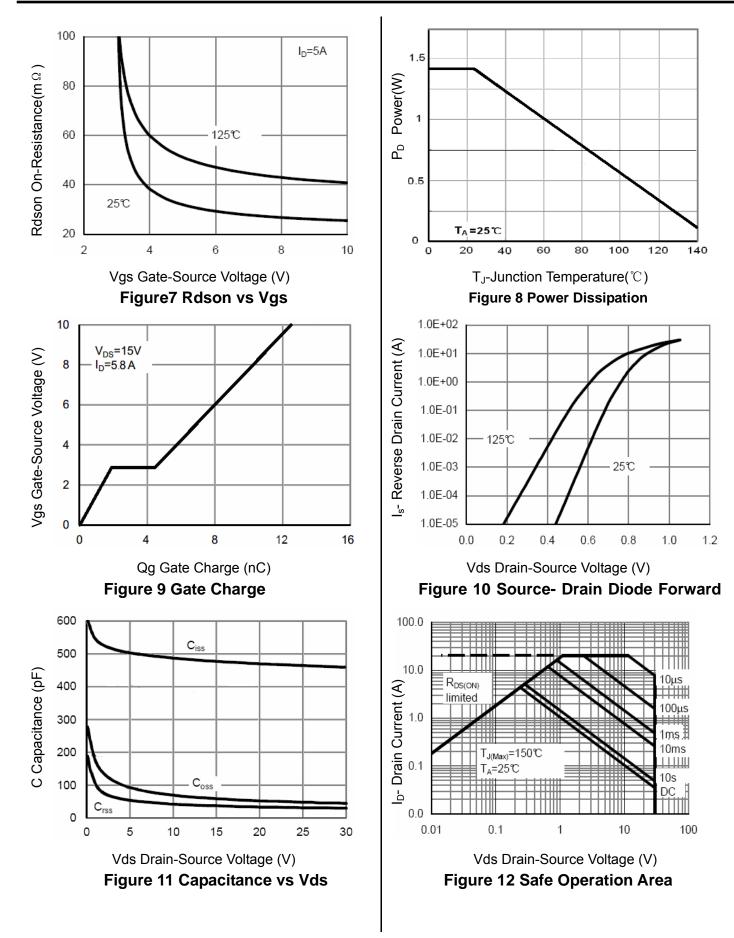
Figure 1:Switching Test Circuit



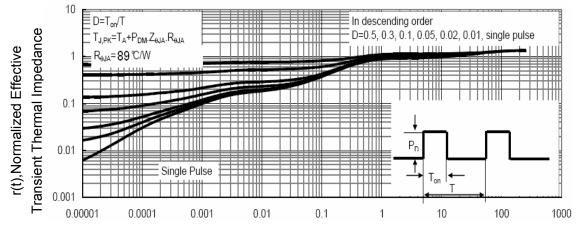


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# NCE3404



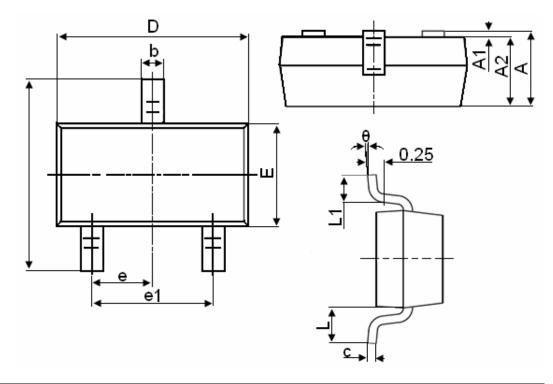




Square Wave Pluse Duration(sec) Figure 13 Normalized Maximum Transient Thermal Impedance



## **SOT-23 Package Information**



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

#### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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